Notice for TAIYO YUDEN Products

[For High Quality and/or Reliability Equipment (Automotive Electronic Equipment / Industrial Equipment)]

Please read this notice before using the TAIYO YUDEN products.

I REMINDERS

Product information in this catalog is as of October 2018. All of the contents specified herein are subject to change without notice due to technical improvements, etc. Therefore, please check for the latest information carefully before practical application or use of our products.

Please note that TAIYO YUDEN shall not be in any way responsible for any damages and defects in products or equipment incorporating our products, which are caused under the conditions other than those specified in this catalog or individual product specification sheets.

- Please contact TAIYO YUDEN for further details of product specifications as the individual product specification sheets are available.
- Please conduct validation and verification of our products in actual condition of mounting and operating environment before using our products.
- The products listed in this catalog are intended for use in general electronic equipment (e.g., AV equipment, OA equipment, home electric appliances, office equipment, information and communication equipment), medical equipment classified as Class I or II by IMDRF, industrial equipment, and automotive interior applications, etc. Please be sure to contact TAIYO YUDEN for further information before using the products for any equipment which may directly cause loss of human life or bodily injury (e.g., transportation equipment including, without limitation, automotive powertrain control system, train control system, and ship control system, traffic signal equipment, medical equipment classified as Class III by IMDRF).

Please do not incorporate our products into any equipment requiring high levels of safety and/or reliability (e.g., aerospace equipment, aviation equipment*, medical equipment classified as Class IV by IMDRF, nuclear control equipment, undersea equipment, military equipment).

*Note: There is a possibility that our products can be used only for aviation equipment that does not directly affect the safe operation of aircraft (e.g., in-flight entertainment, cabin light, electric seat, cooking equipment) if such use meets requirements specified separately by TAIYO YUDEN. Please be sure to contact TAIYO YUDEN for further information before using our products for such aviation equipment.

When our products are used even for high safety and/or reliability-required devices or circuits of general electronic equipment, it is strongly recommended to perform a thorough safety evaluation prior to use of our products and to install a protection circuit as necessary.

Please note that unless you obtain prior written consent of TAIYO YUDEN, TAIYO YUDEN shall not be in any way responsible for any damages incurred by you or third parties arising from use of the products listed in this catalog for any equipment requiring inquiry to TAIYO YUDEN or prohibited for use by TAIYO YUDEN as described above.

- Information contained in this catalog is intended to convey examples of typical performances and/or applications of our products and is not intended to make any warranty with respect to the intellectual property rights or any other related rights of TAIYO YUDEN or any third parties nor grant any license under such rights.
- Please note that the scope of warranty for our products is limited to the delivered our products themselves and TAIYO YUDEN shall not be in any way responsible for any damages resulting from a fault or defect in our products. Notwithstanding the foregoing, if there is a written agreement (e.g., supply and purchase agreement, quality assurance agreement) signed by TAIYO YUDEN and your company, TAIYO YUDEN will warrant our products in accordance with such agreement.
- The contents of this catalog are applicable to our products which are purchased from our sales offices or authorized distributors (hereinafter "TAIYO YUDEN's official sales channel"). Please note that the contents of this catalog are not applicable to our products purchased from any seller other than TAIYO YUDEN's official sales channel.

Caution for Export

Some of our products listed in this catalog may require specific procedures for export according to "U.S. Export Administration Regulations", "Foreign Exchange and Foreign Trade Control Law" of Japan, and other applicable regulations. Should you have any questions on this matter, please contact our sales staff.

Automotive Application Guide

We classify automotive electronic equipment into the following four application categories and set usable application categories for each of our products. When using our products for automotive electronic equipment, please be sure to check such application categories and use our products accordingly. Should you have any questions on this matter, please contact us.

Category	Automotive Electronic Equipment (Typical Example)
	Engine ECU (Electronically Controlled Fuel Injector) Cruise Control Unit
	• 4WS (4 Wheel Steering)
POWERTRAIN	Automatic Transmission
	Power Steering
	HEV/PHV/EV Core Control (Battery, Inverter, DC-DC)
	Automotive Locator (Car location information providing device), etc.
	ABS (Anti-Lock Brake System)
SAFETY	ESC (Electronic Stability Control)
57 (i E i i	• Airbag
	ADAS (Equipment that directly controls running, turning and stopping), etc.
	• Wiper
	Automatic Door
	Power Window
	Keyless Entry System
BODY & CHASSIS	Electric Door Mirror
	Interior Lighting LED Headlight
	• TPMS (Tire Pressure Monitoring System)
	Anti-Theft Device (Immobilizer), etc.
	Car Infotainment System
	• ITS/Telematics System
INFOTAINMENT	Instrument Cluster
	• ADAS (Sensor, Equipment that is not interlocked with safety equipment or powertrain), etc.

MULTILAYER CERAMIC CAPACITORS



PART NUMBER

J	М	Κ	3	1	6	Δ	В	J	1	0	6	М	L	Н	Т	Δ
1										$\overline{\mathcal{O}}$		8				

①Rated voltage

Code	Rated voltage[VDC]
А	4
J	6.3
L	10
E	16
Т	25
G	35
U	50
Н	100
Q	250
S	630

 Ode
 Series name

 M
 Multilayer ceramic capacitor

 V
 Multilayer ceramic capacitor for high frequency

 W
 LW reverse type multilayer capacitor

Image: Second second

 $\Delta =$ Blank space

④Dimension(L×W)

Туре	Dimensions (L×W)[mm]	EIA (inch)
063	0.6 × 0.3	0201
105	1.0 × 0.5	0402
105	0.52 × 1.0 💥	0204
107	1.6 × 0.8	0603
	0.8 × 1.6 💥	0306
010	2.0 × 1.25	0805
212	1.25 × 2.0 💥	0508
316	3.2 × 1.6	1206
325	3.2 × 2.5	1210
432	4.5 × 3.2	1812

Note : &LW reverse type($\Box WK$) only

ode	Туре	L[mm]	W[mm]	T[mm]
Δ	ALL	Standard	Standard	Standard
	063	0.6±0.05	0.3±0.05	0.3±0.05
	105	1.0±0.10	0.5±0.10	0.5±0.10
A	107	1.6+0.15/-0.05	0.8+0.15/-0.05	0.8+0.15/-0.05
	212	2.0+0.15/-0.05	$1.25 \pm 0.15 = 0.05$	0.85±0.10
	212	2.0+0.13/-0.03	1.25+0.15/-0.05	1.25+0.15/-0.05
	316	3.2 ± 0.20	1.6±0.20	1.6±0.20
	325	3.2 ± 0.30	2.5±0.30	2.5±0.30
	105	1.0+0.15/-0.05	0.5+0.15/-0.05	0.5+0.15/-0.05
	107	1.6+0.20/-0	0.8+0.20/-0	0.8+0.20/-0
В 212		1.05 0.00 / 0	0.85±0.10	
	2.0+0.20/-0	1.25+0.20/-0	1.25+0.20/-0	
	316	3.2±0.30	1.6±0.30	1.6±0.30
	105	1.0+0.20/-0	0.5+0.20/-0	0.5+0.20/-0
С	107	1.6+0.25/-0	0.8+0.25/-0	0.8+0.25/-0
	212	2.0+0.25/-0	1.25+0.25/-0	1.25+0.25/-0
	212	2.0±0.15	1.25±0.15	0.85 ± 0.15
К 316	216	3.2 ± 0.20	1.6±0.20	1.15±0.20
	316	3.2±0.20	1.0±0.20	1.6±0.20
	325	3.2±0.50	2.5±0.30	2.5±0.30
		Note: cf. STANDARD EXTERN	IAL DIMENSIONS	_=

$\textcircled{\begin{tabular}{ll} 6 \end{tabular}} Temperature characteristics code \end{tabular}$

High dielectric	type								
Code	Applicable		Applicable standard		Temperature range[°C]	Ref. Temp.[°C]	Capacitance change	Capacitance tolerance	Tolerance code
D.I.				05	1 150/	±10%	K		
BJ	EIA	X5R	$-55 \sim + 85$	25	±15%	±20%	м		
C6	EIA	X6S	$-55 \sim +105$	25	±22%	±10%	К		
00	LIA	703	55.4 1 105	25	± 22 %	±20%	М		
В7	EIA X7R -55~+125 25 ±15%		±15%	±10%	к				
Вл	LIA	7/1	33.4 1123	25	± 1370	±20%	М		
C7	EIA	X7S	$-55 \sim +125$	25	±22%	±10%	К		
07		7/5	33 * 1 123	25	<u> </u>	±20%	М		
D7	EIA		x7T −55~+12	$-55 \sim +125$	25	+22%/-33%	±10%	К	
07	LIA	~/1	55 * 1 125	25	1 22 /0/ 33 /0	±20%	М		

for High Quality Equipment

Temperature compensating type

Code		icable Idard	Temperature range[°C]	Ref. Temp.[°C]	Capacitance change	Capacitance tolerance	Tolerance code												
		JIS CG	-55~+125	20		±0.1pF	В												
					0 L 20 /20	±0.25pF	С												
CG						$\pm 0.5 pF$	D												
UG		A COG													$-55 \sim +125$		0±30ppm∕°C	±1pF	F
	EIA			25		±2%	G												
						±5%	J												

⑦Nominal capacitance

Code (example)	Nominal capacitance
0R5	0.5pF
010	1pF
100	10pF
101	100pF
102	1,000pF
103	0.01 <i>µ</i> F
104	0.1 <i>µ</i> F
105	1.0 <i>µ</i> F
106	10 <i>µ</i> F
107	100 <i>µ</i> F
Note : R=Decim	al point

(9) Thickness Code Thickness[mm] Ρ 0.3 Т 0.5 V 0.7(107type or more) С А 0.8 D 0.85(212type or more) F 1.15 G 1.25 L 1.6 1.9 Ν М 2.5

Output to the second	blerance
Code	Capacitance tolerance
А	±0.05pF
В	±0.1pF
С	±0.25pF
D	±0.5pF
G	±2%
J	$\pm 5\%$
К	±10%
М	±20%

Н	MLCC for Industrial and Automotive				
11)Packaging	7				
Code	Packaging				
F	ϕ 178mm Taping (2mm pitch)				
R	ϕ 178mm Embossed Taping (4mm pitch)				
Т	ϕ 178mm Taping (4mm pitch)				
Р	ϕ 178mm Taping (4mm pitch, 1000 pcs/reel)				
	325 type(Thickness code M)				

Special code

12Internal code

①Special code

Code

Winternal code	
Code	Internal code
Δ	Standard

for High Quality Equipment





※ LW reverse type

- ()		Dime	nsion [mm] (inch)		
Type(EIA)	L	W	Т	*1	е
□MK063(0201)	0.6 ± 0.03 (0.024 ± 0.001)	0.3 ± 0.03 (0.012 \pm 0.001)	0.3±0.03 (0.012±0.001)	т	0.15 ± 0.05 (0.006 ± 0.002)
□MK105(0402)	1.0±0.05	0.5 ± 0.05	0.5±0.05	v	0.25±0.10
□MF105(0402) □WK105(0204)※	(0.039 ± 0.002) 0.52 ± 0.05	(0.020 ± 0.002) 1.0 ± 0.05	(0.020 ± 0.002) 0.3 ± 0.05	Р	(0.010 ± 0.004) 0.18 ± 0.08
□MK107(0603)	(0.020 ± 0.002) 1.6 ± 0.10	(0.039±0.002) 0.8±0.10	(0.012±0.002) 0.8±0.10	A	(0.007±0.003) 0.35±0.25
□MF107(0603)	(0.063 ± 0.004) 1.6 \pm 0.10	(0.031 ± 0.004) 0.8 ± 0.10	(0.031 ± 0.004) 0.8 ± 0.10		(0.014 ± 0.010) $0.35 \pm 0.3/-0.25$
□MJ107(0603)	(0.063 ± 0.004) 1.6 ± 0.10	(0.031 ± 0.004) 0.8 ± 0.10	(0.031 ± 0.004) 0.7 ± 0.10	A	$(0.014 \pm 0.012 - 0.010)$ 0.35 ± 0.25
□VS107(0603)	(0.063 ± 0.004)	(0.031±0.004)	(0.028±0.004)	С	(0.014±0.010)
□WK107(0306)※	0.8±0.10 (0.031±0.004)	1.6 ± 0.10 (0.063 ± 0.004)	0.5 ± 0.05 (0.020 ± 0.002)	V	0.25 ± 0.15 (0.010 ± 0.006)
□MK212(0805)	2.0±0.10	1.25±0.10	0.85±0.10 (0.033±0.004)	D	0.5 ± 0.25
□MF212(0805)	(0.079±0.004)	(0.049±0.004)	1.25 ± 0.10 (0.049 ± 0.004)	G	(0.020±0.010)
	2.0±0.10	1.25±0.10	0.85 ± 0.10 (0.033 ± 0.004)	D	0.5+0.35/-0.25 (0.020+0.014/-0.010)
□MJ212(0805)	(0.079 ± 0.004)	(0.049 ± 0.004)	1.25 ± 0.10 (0.049 ± 0.004)	G	
□VS212(0805)	2.0 ± 0.10 (0.079 ± 0.004)	1.25 ± 0.10 (0.049 ± 0.004)	0.85±0.10 (0.033±0.004)	D	0.5±0.25 (0.020±0.010)
□WK212(0508)※	1.25 ± 0.15 (0.049 ± 0.006)	2.0 ± 0.15 (0.079 ± 0.006)	0.85 ± 0.10 (0.033 ± 0.004)	D	0.3±0.2 (0.012±0.008)
□MK316(1206)	3.2±0.15	1.6±0.15	1.15 ± 0.10 (0.045 ± 0.004)	F	0.5+0.35/-0.25
□MF316(1206)	(0.126±0.006)	(0.063 ± 0.006)	1.6±0.20 (0.063±0.008)	L	(0.020+0.014/-0.010)
□MJ316(1206)	3.2±0.15	1.6±0.15	1.15±0.10 (0.045±0.004)	F	0.6+0.4/-0.3
LIMU310(1200)	(0.126±0.006)	(0.063±0.006)	1.6±0.20 (0.063±0.008)	L	(0.024+0.016/-0.012)
			1.15±0.10 (0.045±0.004)	F	
□MK325(1210) □MF325(1210)	3.2 ± 0.30 (0.126 ± 0.012)	2.5 ± 0.20 (0.098 ± 0.008)	1.9 ± 0.20 (0.075 ± 0.008)	N	0.6 ± 0.3 (0.024 ± 0.012)
··-··		,	2.5±0.20 (0.098±0.008)	м	
	0.0 + 0.00	0.5 - 0.00	1.9±0.20	N	
□MJ325(1210)	3.2 ± 0.30 (0.126 ± 0.012)	2.5 ± 0.20 (0.098 ± 0.008)	$\begin{array}{r} (0.075 \pm 0.008) \\ 2.5 \pm 0.20 \\ (0.098 \pm 0.008) \end{array}$	м	$\begin{array}{c} 0.6 \!+\! 0.4 / \!-\! 0.3 \\ (0.024 \!+\! 0.016 / \!-\! 0.012) \end{array}$
	4.5±0.40	3.2±0.30	(0.098±0.008) 2.5±0.20	м	0.9±0.6

for High Quality Equipment

STANDARD QUANTITY

Туре	EIA (inch)	Dime	nsion	Standard qu	uantity[pcs]	
туре	EIA (Inch)	[mm]	Code	Paper tape	Embossed tape	
063	0201	0.3	Т	15000	-	
105	0402	0.5	V	10000		
105	0204 💥	0.30	Р	10000	_	
		0.7	С	4000	_	
		0.8	A	4000	_	
107	107 0603	0.8	A	3000 (Soft Termination)	-	
		0.8	А	-	3000 (Soft Termination	
	0306 💥	0.50	V	-	4000	
		0.85	D	4000	_	
	0005	1.25	G	-	3000	
212	0805	1.25	G	-	2000 (Soft Termination	
	0508 💥	0.85	D	4000	_	
010	1000	1.15	F	-	3000	
316	1206	1.6	L	-	2000	
		1.15	F		2000	
325	1210				2000	
		2.5	М	-	500(T), 1000(P)	
432	1812	2.5	М	_	500	

Soft Termination Multilayer Ceramic Capacitors

• 107TYPE (Dimension: 1.6×0.8 mm JIS: 1608 EIA: 0603) [Temperature Characteristic B7 : X7R(-55~+125°C)] 0.8mm thickness(A)

Part number 1	Part number 2	Rated voltage [V]	Tempe charact	erature eristics	Capacitance [F]	Capacitance tolerance [%]	tan δ [%]	HTLT Rated voltage x %	Thickness ^{*3} [mm]	Note
TMJ107BB7473[AHT				X7R	0.047 μ	±10, ±20	3.5	200	0.8+0.20/-0	*1, *2
TMJ107BB7104[AHT				X7R	0.1 µ	±10, ±20	3.5	200	0.8+0.20/-0	*1, *2
TMJ107BB7224[]AHT		25		X7R	0.22 μ	±10, ±20	10	150	0.8+0.20/-0	*1, *2
TMJ107BB7474[]AHT				X7R	0.47 μ	±10, ±20	10	150	0.8+0.20/-0	*1, *2
TMJ107CB7105[AHR				X7R	1 μ	±10, ±20	10	150	0.8+0.25/-0	*1, *2
GMJ107BB7473[AHT				X7R	0.047 μ	±10, ±20	3.5	200	0.8+0.20/-0	*1, *2
GMJ107BB7104[AHT				X7R	0.1 μ	±10, ±20	3.5	200	0.8+0.20/-0	*1, *2
GMJ107BB7224[AHT		35		X7R	0.22 μ	±10, ±20	10	150	0.8+0.20/-0	*1, *2
GMJ107BB7474[AHT				X7R	0.47 μ	±10, ±20	10	150	0.8+0.20/-0	*1, *2
GMJ107CB7105[AHR				X7R	1μ	±10, ±20	10	150	0.8+0.25/-0	*1, *2
UMJ107AB7102[AHT				X7R	1000 p	±10, ±20	3.5	200	0.8+0.15/-0.05	*1, *2
UMJ107AB7222[AHT				X7R	2200 p	±10, ±20	3.5	200	0.8+0.15/-0.05	*1, *2
UMJ107BB7472[]AHT				X7R	4700 p	±10, ±20	3.5	200	0.8+0.20/-0	*1, *2
UMJ107BB7103[]AHT		50		X7R	0.01 µ	±10, ±20	3.5	200	0.8+0.20/-0	*1, *2
UMJ107BB7223[AHT				X7R	0.022 µ	±10, ±20	3.5	200	0.8+0.20/-0	*1, *2
UMJ107BB7473[AHT				X7R	0.047 μ	±10, ±20	3.5	200	0.8+0.20/-0	*1, *2
UMJ107BB7104[]AHT				X7R	0.1 μ	±10, ±20	3.5	200	0.8+0.20/-0	*1, *2
HMJ107AB7102[AHT				X7R	1000 p	±10, ±20	3.5	200	0.8+0.15/-0.05	*1, *2
HMJ107AB7222[]AHT		1		X7R	2200 p	±10, ±20	3.5	200	0.8+0.15/-0.05	*1, *2
HMJ107BB7472[AHT		1		X7R	4700 p	±10, ±20	3.5	200	0.8+0.20/-0	*1, *2
HMJ107BB7103[AHT		100		X7R	0.01 µ	±10, ±20	3.5	200	0.8+0.20/-0	*1, *2
HMJ107BB7223[]AHT		1		X7R	0.022 μ	±10, ±20	3.5	200	0.8+0.20/-0	*1, *2
HMJ107BB7473[]AHT		1		X7R	0.047 μ	±10, ±20	3.5	200	0.8+0.20/-0	*1, *2
HMJ107BB7104[AHT		1		X7R	0.1 μ	±10, ±20	3.5	200	0.8+0.20/-0	*1, *2

•212TYPE (Dimension:2.0 × 1.25mm JIS:2012 EIA:0805) [Temperature Characteristic B7 : X7R($-55 \sim +125^{\circ}$ C), C7 : X7S($-55 \sim +125^{\circ}$ C)] 0.85mm thickness(D), 1.25mm thickness(G)

Part number 1	Part number 2	Rated voltage		erature	Capacitance	Capacitance	tan δ	HTLT	Thickness ^{*3} [mm]	Note
		[V]	charact	teristics	[F]	tolerance [%]	[%]	Rated voltage x %		
JMJ212CB7106[]GHT		6.3		X7R	10 µ	±10, ±20	10	150	1.25+0.25/-0	*1, *2
EMJ212CB7225[]GHT		16		X7R	2.2 μ	±10, ±20	10	150	1.25+0.25/-0	*1, *2
EMJ212CB7475[]GHT		10		X7R	4.7 μ	±10, ±20	10	150	1.25+0.25/-0	*1, *2
TMJ212CB7225[]GHT		25		X7R	2.2 μ	±10, ±20	10	150	1.25+0.25/-0	*1, *2
GMJ212CB7105[]GHT		35		X7R	1μ	±10, ±20	10	150	1.25+0.25/-0	*1, *2
UMJ212BB7103[]GHT				X7R	0.01 µ	±10, ±20	3.5	200	1.25+0.20/-0	*1, *2
UMJ212BB7223[]GHT				X7R	0.022 μ	±10, ±20	3.5	200	1.25+0.20/-0	*1, *2
UMJ212BB7473[]GHT				X7R	0.047 μ	±10, ±20	3.5	200	1.25+0.20/-0	*1, *2
UMJ212BB7104[]GHT		50		X7R	0.1 μ	±10, ±20	3.5	200	1.25+0.20/-0	*1, *2
UMJ212BB7224[]GHT				X7R	0.22 μ	±10, ±20	3.5	200	1.25+0.20/-0	*1, *2
UMJ212CC7474[]GHTE				X7S	0.47 μ	±10, ±20	3.5	150	1.25+0.25/-0	*1, *2
UMJ212CB7105[GHT				X7R	1 μ	±10, ±20	10	150	1.25+0.25/-0	*1, *2
HMJ212KB7102[]DHT				X7R	1000 p	±10, ±20	3.5	200	0.85±0.15	*1, *2
HMJ212KB7222[]DHT				X7R	2200 p	±10, ±20	3.5	200	0.85 ± 0.15	*1, *2
HMJ212BB7472[]GHT				X7R	4700 p	±10, ±20	3.5	200	1.25+0.20/-0	*1, *2
HMJ212BB7103[]GHT				X7R	0.01 µ	±10, ±20	3.5	200	1.25+0.20/-0	*1, *2
HMJ212BB7223[]GHT		100		X7R	0.022 μ	±10, ±20	3.5	200	1.25+0.20/-0	*1, *2
HMJ212BB7473[]GHT				X7R	0.047 μ	±10, ±20	3.5	200	1.25+0.20/-0	*1, *2
HMJ212BB7104[]GHT				X7R	0.1 μ	±10, ±20	3.5	200	1.25+0.20/-0	*1, *2
HMJ212BB7224[]GHT				X7R	0.22 μ	±10, ±20	3.5	200	1.25+0.20/-0	*1, *2
HMJ212CC7474[]GHTE				X7S	0.47 μ	±10, ±20	3.5	150	1.25+0.25/-0	*1, *2
QMJ212KB7102[]DHT				X7R	1000 p	±10, ±20	2.5	150	0.85 ± 0.15	*1, *2
QMJ212KB7222[DHT				X7R	2200 p	±10, ±20	2.5	150	0.85 ± 0.15	*1, *2
QMJ212BB7472[]GHT		250		X7R	4700 p	±10, ±20	2.5	150	1.25+0.20/-0	*1, *2
QMJ212BB7103[]GHT				X7R	0.01 µ	±10, ±20	2.5	150	1.25+0.20/-0	*1, *2
QMJ212BB7223[]GHT				X7R	0.022 µ	±10, ±20	2.5	150	1.25+0.20/-0	*1, *2

CERAMIC CAPACITORS

—316TYPE (Dimension:3.2 × 1.6mm JIS:3216 EIA:1206)

[Temperature Characteristic B7 : X7R(-55~+125°C), C7 : X7S(-55~+125°C)] 1.15mm thickness(F), 1.6mm thickness(L)

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Part number 1	Part number 2	Rated voltage [V]		erature teristics	Capacitance [F]	Capacitance tolerance [%]	tan δ [%]	HTLT Rated voltage x %	Thickness ^{*3} [mm]	Note
LMJ316BB7226[]LHT		10		X7R	22 μ	±10, ±20	10	150	1.6±0.30	*1, *2
EMJ316BB7475[]LHT		16		X7R	4.7 μ	±10, ±20	10	150	1.6 ± 0.30	*1, *2
EMJ316BB7106[]LHT		10		X7R	10 µ	±10, ±20	10	150	1.6 ± 0.30	*1, *2
TMJ316BB7474[LHT				X7R	0.47 μ	±10, ±20	3.5	200	1.6 ± 0.30	*1, *2
TMJ316BB7475[LHT		25		X7R	4.7 μ	±10, ±20	10	150	1.6 ± 0.30	*1, *2
TMJ316BB7106[LHT		1		X7R	10 µ	±10, ±20	10	150	1.6 ± 0.30	*1, *2
GMJ316BB7474[LHT				X7R	0.47 μ	±10, ±20	3.5	200	1.6 ± 0.30	*1, *2
GMJ316AB7225[LHT		35		X7R	2.2 μ	±10, ±20	10	150	1.6 ± 0.20	*1, *2
GMJ316BB7475[LHT		30		X7R	4.7 μ	±10, ±20	10	150	1.6 ± 0.30	*1, *2
GMJ316BB7106[LHT		1		X7R	10 <i>µ</i>	±10, ±20	10	150	1.6 ± 0.30	*1, *2
UMJ316BB7473[LHT				X7R	0.047 μ	±10, ±20	3.5	200	1.6 ± 0.30	*1, *2
UMJ316BB7104[LHT		1		X7R	0.1 μ	±10, ±20	3.5	200	1.6 ± 0.30	*1, *2
UMJ316BB7224[LHT		1		X7R	0.22 μ	±10, ±20	3.5	200	1.6 ± 0.30	*1, *2
UMJ316BB7474[]LHT		50		X7R	0.47 μ	±10, ±20	3.5	200	1.6 ± 0.30	*1, *2
UMJ316BB7105[]LHT		1		X7R	1 μ	±10, ±20	3.5	200	1.6 ± 0.30	*1, *2
UMJ316AB7225[]LHT		1		X7R	2.2 μ	±10, ±20	10	150	1.6 ± 0.20	*1, *2
UMJ316BC7475[LHTE				X7S	4.7 μ	±10, ±20	2.5	150	1.6 ± 0.30	*1, *2
HMJ316 B7102[]FHT				X7R	1000 p	±10, ±20	3.5	200	1.15±0.10	*1, *2
HMJ316 B7222[]FHT		1		X7R	2200 p	±10, ±20	3.5	200	1.15±0.10	*1, *2
HMJ316 B7472[]FHT		1		X7R	4700 p	±10, ±20	3.5	200	1.15±0.10	*1, *2
HMJ316KB7103[FHT		Ţ		X7R	0.01 µ	±10, ±20	3.5	200	1.15 ± 0.20	*1, *2
HMJ316BB7223[]LHT		1		X7R	0.022 µ	±10, ±20	3.5	200	1.6 ± 0.30	*1, *2
HMJ316BB7473[LHT		100		X7R	0.047 μ	±10, ±20	3.5	200	1.6 ± 0.30	*1, *2
HMJ316BB7104[]LHT		1		X7R	0.1 μ	±10, ±20	3.5	200	1.6 ± 0.30	*1, *2
HMJ316BB7224[]LHT		1		X7R	0.22 μ	±10, ±20	3.5	200	1.6 ± 0.30	*1, *2
HMJ316BB7474[]LHT]		X7R	0.47 μ	±10, ±20	3.5	200	1.6 ± 0.30	*1, *2
HMJ316BB7105[LHT]		X7R	1 μ	±10, ±20	3.5	200	1.6 ± 0.30	*1, *2
HMJ316BC7225[]LHTE				X7S	2.2 μ	±10, ±20	3.5	150	1.6 ± 0.30	*1, *2
QMJ316 B7102[FHT				X7R	1000 p	±10, ±20	2.5	150	1.15±0.10	*1, *2
QMJ316 B7222[]FHT]		X7R	2200 p	±10, ±20	2.5	150	1.15±0.10	*1, *2
QMJ316 B7472[]FHT		Ţ		X7R	4700 p	±10, ±20	2.5	150	1.15±0.10	*1, *2
QMJ316KB7103[FHT		250		X7R	0.01 µ	±10, ±20	2.5	150	1.15 ± 0.20	*1, *2
QMJ316BB7223[]LHT]		X7R	0.022 µ	±10, ±20	2.5	150	1.6 ± 0.30	*1, *2
QMJ316BB7473[LHT]		X7R	0.047 μ	±10, ±20	2.5	150	1.6 ± 0.30	*1, *2
QMJ316BB7104[LHT				X7R	0.1 μ	±10, ±20	2.5	150	1.6 ± 0.30	*1, *2
SMJ316 B7102[]FHT				X7R	1000 p	±10, ±20	2.5	120	1.15±0.10	*1, *2
SMJ316 B7222[]FHT]		X7R	2200 p	±10, ±20	2.5	120	1.15±0.10	*1, *2
SMJ316 B7472[]FHT		630		X7R	4700 p	±10, ±20	2.5	120	1.15±0.10	*1, *2
SMJ316KB7103[FHT]		X7R	0.01 µ	±10, ±20	2.5	120	1.15 ± 0.20	*1, *2
SMJ316BB7223 LHT		Ţ		X7R	0.022 µ	±10, ±20	2.5	120	1.6 ± 0.30	*1, *2

● 325TYPE(Dimension:3.2×2.5mm JIS:3225 EIA:1210)

Part number 1	Part number 2	Rated voltage	Tempe	erature	Capacitance	Capacitance	tan δ	HTLT	Thickness ^{*3} [mm]	Note
Fart number i	Fart number 2	[V]	charact	teristics	[F]	tolerance [%]	[%]	Rated voltage x %	Inickness [mm]	Note
JMJ325KB7476[]MHP		6.3		X7R	47 μ	±10, ±20	10	150	2.5 ± 0.30	*1, *2
EMJ325KB7226[]MHP		16		X7R	22 μ	±10, ±20	10	150	2.5 ± 0.30	*1, *2
MJ325AB7475[]MHP		25		X7R	4.7 μ	±10, ±20	5	150	2.5±0.30	*1, *2
MJ325KB7106[]MHP		23		X7R	10 <i>µ</i>	±10, ±20	10	150	2.5 ± 0.30	*1, *2
MJ325AB7475[]MHP		35		X7R	4.7 μ	±10, ±20	5	150	2.5±0.30	*1, *2
GMJ325KB7106[]MHP				X7R	10 <i>µ</i>	±10, ±20	10	150	2.5 ± 0.30	*1, *2
JMJ325AB7225[]MHP				X7R	2.2 μ	±10, ±20	3.5	200	2.5 ± 0.30	*1, *2
IMJ325AB7475[]MHP		50		X7R	4.7 μ	±10, ±20	5	150	2.5±0.30	*1, *2
IMJ325KB7106[]MHP				X7R	10 <i>µ</i>	±10, ±20	10	150	2.5 ± 0.30	*1, *2
IMJ325 B7223[]NHT				X7R	0.022 µ	±10, ±20	3.5	200	1.9±0.20	*1, *
IMJ325 B7473[]NHT		T		X7R	0.047 μ	±10, ±20	3.5	200	1.9±0.20	*1, *
IMJ325 B7104[]NHT		Ι		X7R	0.1 μ	±10, ±20	3.5	200	1.9±0.20	*1, *
IMJ325 B7224[]NHT		100		X7R	0.22 μ	±10, ±20	3.5	200	1.9±0.20	*1, *
IMJ325 B7474[]NHT		100		X7R	0.47 μ	±10, ±20	3.5	200	1.9±0.20	*1, *
MJ325 B7105[]NHT		T		X7R	1 μ	±10, ±20	3.5	200	1.9±0.20	*1, *:
IMJ325AB7225[]MHP		T		X7R	2.2 μ	±10, ±20	3.5	200	2.5 ± 0.30	*1, *:
MJ325KC7475[]MHPE		T		X7S	4.7 μ	±10, ±20	3.5	150	2.5 ± 0.30	*1, *:
MJ325 B7223 NHT				X7R	0.022 µ	±10, ±20	2.5	150	1.9±0.20	*1, *
QMJ325 B7473[]NHT		250		X7R	0.047 μ	±10, ±20	2.5	150	1.9±0.20	*1, *
QMJ325 B7104[]NHT		250		X7R	0.1 μ	±10, ±20	2.5	150	1.9±0.20	*1, *
QMJ325 B7224[]NHT		T I		X7R	0.22 μ	±10, ±20	2.5	150	1.9±0.20	*1, *
MJ325 B7223[]NHT		630		X7R	0.022 µ	±10, ±20	2.5	120	1.9±0.20	*1, *
MJ325 B7473[NHT		030		X7R	0.047 μ	±10, ±20	2.5	120	1.9±0.20	*1, *

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Multilayer Ceramic Capacitors

PACKAGING

①Minimum Quantity

_ ()	Thick	ness	Standard o	uantity [pcs]
Type(EIA)	mm	code	Paper tape	Embossed tape
□MK021(008004)	0.105	к		50000
□VS021(008004)	0.125	n	_	50000
MK042(01005)	0.2	C, D		40000
□VS042(01005)	0.2	С		40000
□MK063(0201)	0.3	P,T	15000	—
□WK105(0204) 💥	0.3	Р	10000	_
	0.13	Н	_	20000
	0.18	E	_	15000
□MK105(0402)	0.2	С	20000	-
□MF105(0402)	0.3	Р	15000	-
	0.5	V	10000	_
□VK105(0402)	0.5	W	10000	-
MK107(0603)	0.45	К	4000	-
□WK107(0306) ※	0.5	V	-	4000
□MF107(0603)	0.8	А	4000	-
□VS107(0603)	0.7	С	4000	-
□MJ107(0603)	0.8	А	3000	3000
□MK212(0805)	0.45	К	4000	
□WK212(0508) ※	0.85	D	4000	_
□MF212(0805)	1.25	G	_	3000
□VS212(0805)	0.85	D	4000	_
	0.85	D	4000	_
□MJ212(0805)	1.25	G	-	2000
	0.85	D	4000	-
□MK316(1206)	1.15	F	_	3000
□MF316(1206)	1.6	L	-	2000
	1.15	F	-	3000
□MJ316(1206)	1.6	L	_	2000
	0.85	D		
	1.15	F		
□MK325(1210)	1.9	Ν	7 -	2000
□MF325(1210)	2.0max.	Y	1	
	2.5	М	_	1000
	1.9	Ν	—	2000
□MJ325(1210)	2.5	М	—	500(T), 1000(P)
□MK432(1812)	2.5	М	-	500

Note : 💥 LW Reverse type.

(2) Taping material



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TAIYO YUDEN



3 Representative taping dimensions





Type(EIA)	Chip	Cavity	Insertion Pitch	Tape Tł	nickness			
Type(EIA)	А	В	F	Т	T1			
□MK063(0201)	0.37	0.67		0.45max.	0.42max.			
□WK105(0204) ※			2.0 ± 0.05	0.45max.	0.42max.			
□MK105(0402) (*1 C)	0.65	1.15	2.0 ± 0.05	0.4max.	0.3max.			
□MK105(0402) (*1 P)				0.45max.	0.42max.			
Note *1 Thickness, C:0.2mm ,P:0.3mm. ※ LW Reverse type. Unit:mm								



Type(EIA)	Chip (Cavity	Insertion Pitch	Tape Thickness
	A	В	F	Т
□MK105 (0402) □MF105 (0402) □VK105 (0402)	0.65	1.15	2.0±0.05	0.8max.

Unit:mm





Type(EIA)	Chip (Cavity	Insertion Pitch	Tape Thickness	
Type(LIA)	А	В	F	Т	
□MK107(0603)					
□WK107(0306) 💥	1.0	1.8		1.1max.	
□MF107(0603)			40104		
MK212(0805)	1.05	0.4	4.0±0.1		
□WK212(0508) 💥	1.65	2.4		1.1max.	
DMK316(1206)	2.0	3.6			
Note:Taping size might	be different depending on	the size of the product.	※ LW Reverse type.	Unit : mm	

 0.9 ± 0.05

Note: Taping size might be different depending on the size of the product. % LW Reverse type.





Type(EIA)	Chip (Cavity	Insertion Pitch	Tape Thickness		
Type(EIA)	А	В	F	К	Т	
□MK021(008004)	0 1 2 5	0.27	101000		0.25max.	
□VS021(008004)	0.135	0.27		0.5max.		
□MK042(01005)		0.40	1.0±0.02			
□VS042(01005)	0.23	0.43				

Unit:mm(inch)

Unit:mm



Type(EIA)	Chip (Cavity	Insertion Pitch	Tape Thickness		
Type(EIA)	А	В	F	К	Т	
□MK105(0402)	0.6	1.1	2.0±0.1	0.6max	0.2±0.1	
□WK107(0306) ※	1.0	1.8		1.3max.	0.25 ± 0.1	
□MK212(0805)	1.65	2.4		3.4max.		
DMF212(0805)	1.05	2.4				
□MK316(1206)	2.0	3.6	4.0±0.1		0.6max.	
□MF316(1206)	2.0	5.0			0.0max.	
□MK325(1210)	2.8	3.6				
□MF325(1210)	2.0	5.0				

Note: 💥 LW Reverse type.

Unit:mm



Type(EIA)	Chip (Cavity	Insertion Pitch	Tape Thickness		
Type(EIA)	A	В	F	К	Т	
□MK325(1210)	3.1	4.0	8.0±0.1	4.0max.	0.6max.	
□MK432(1812)	3.7	4.9	8.0±0.1	4.0max.	0.6max.	

Unit : mm

④Trailer and Leader



⑤Reel size



А	В	С	D	E	R
ϕ 178±2.0	<i>ф</i> 50min.	ϕ 13.0±0.2	<i>ф</i> 21.0±0.8	2.0 ± 0.5	1.0
	Т	W			
4mm wide tape	1.5max.	5±1.0			
8mm wide tape	2.5max.	10±1.5	-		
12mm wide tape	2.5max.	14±1.5	Unit : mm		

6 Top Tape Strength

The top tape requires a peel-off force of 0.1 to 0.7N in the direction of the arrow as illustrated below.





RELIABILITY DATA

1.Operating Te	mperature Range					
	Temperature	Standard	—55 to +	- 125°C		
	Compensating(Class1)	High Frequency Type	- 55 to -	- 125 C		
				Specification	Temperature Range	
				В	-25 to +85°C	
Specified			BJ	X5R	−55 to +85°C	
Value			B7	X7R	-55 to $+125^{\circ}$ C	
	High Permittivity (Class2))	C6	X6S	-55 to $+105^{\circ}$ C	
			C7	X7S	-55 to +125°C	
			D7	X7T	-55 to +125°C	
			LD(※)	X5R	$-55 \text{ to } +85^{\circ}\text{C}$	
			Note: 🔆	LD Low distortion k	high value multilayer ceramic capa	citor

2. Storage Co	nditions				
	Temperature	Standard	—55 to +	10E°C	
	Compensating(Class1)	High Frequency Type	- 55 to +	125 C	
				Specification	Temperature Range
			БТ	В	-25 to +85°C
Specified			BJ	X5R	-55 to +85°C
Value			B7	X7R	−55 to +125°C
	High Permittivity (Class2)	C6	X6S	$-55 \text{ to } +105^{\circ}\text{C}$
			C7	X7S	-55 to +125°C
			D7	X7T	-55 to +125°C
			LD(💥)	X5R	−55 to +85°C
			Note: 🗙	LD Low distortion	high value multilayer ceramic capacitor

3. Rated Voltag	ge		
0 10 1	Temperature	Standard	50VDC, 25VDC
Specified Value	Compensating(Class1)	High Frequency Type	50VDC, 25VDC
Value	High Permittivity (Class2))	50VDC, 35VDC, 25VDC, 16VDC, 10VDC, 6.3VDC, 4VDC, 2.5VDC

4. Withstanding	Voltage (Between termina	s)				
0.15.1	Temperature		Standard			
Specified Value	Compensating(Class1)	High F	requency Type	No breakdown o	r damage	
Valuo	High Permittivity (Class2)				
Test			Cla	ass 1	Class 2	
Test Methods and	Applied voltage		Rated	volta × 3	Rated voltage × 2.5	
Remarks	Duration			1 to 5	sec.	
i temar 65	Charge/discharge currer	nt		50mA	max.	7

5. Insulation Re	esistance		
	Temperature	Standard	10000 MΩmin.
Specified	Compensating(Class1)	High Frequency Type	
Value	High Permittivity(Class2)	Note 1	C≦0.047 μF : 10000 MΩ min. C>0.047 μF : 500MΩ• μF
Test	Applied voltage	: Rated voltage	
Methods and	Duration	:60±5 sec.	
Remarks	Charge/discharge current	: 50mA max.	

6. Capacitance	(Tolerance)					
	Temperature Compensating(Class1)	Standard	C□ U□ SL	0.2pF≦C≦5pF 0.2pF≦C≦10pF C>10pF	: ±0.25pF : ±0.5pF : ±5% or ±10%	
Specified Value	Compensating (Class I)	High Frequency Type	СН	0.3pF≦C≦2pF C>2pF	: ±0.1pF : ±5%	
	High Permittivity(Class2))		7, C6, C7, D7, LD(※):: ※LD Low distortion hig	$\pm 10\%$ or $\pm 20\%$ gh value multilayer ceramic	capacitor
			Clas	ss 1	Cla	ass 2
т .		Standard	ł	High Frequency Type	C≦10 <i>µ</i> F	C>10 µF
Test Mathada and	Preconditioning		No	ne	Thermal treatment (a	t 150°C for 1hr) Note 2
Methods and Remarks	Measuring frequency		1MHz	±10%	1kHz±10%	120±10Hz
rtemarks	Measuring voltage Note		0.5 to	5Vrms	1±0.2Vrms	0.5±0.1rms
	Bias application				one	

Specified	Temperature	:	Standard	-	DpF:Q≧400+20C DpF:Q≧1000 (C:N	ominal capacitance)	
Value	Compensating(Class1)	High F	requency Type	Refer	to detailed specification		
	High Permittivity (Class2)	Note	1	BJ, B	7, C6, C7, D7:2.5% max.		
				Cla	ss 1	Clas	s 2
			Standard		High Frequency Type	C≦10 <i>µ</i> F	C>10 µF
	Preconditioning			No	one	Thermal treatment (at	150°C for 1hr) Note 2
Test	Measuring frequey		1MHz±10	D%	1GHz	1kHz±10%	$120\pm10Hz$
Methods and	Measuring voltage Note	1		0.5 to	5Vrms	1±0.2Vrms	$0.5 \pm 0.1 V rms$
Remarks	Bias application					None	
	High Frequency Type						
	Measuring equipment	: HP	4291A				
	Measuring jig	: HP	16192A				

8. Temperatur	re Characteristic (Without vo	ltage application)							
			Tem	perature Charac	teristic [ppm/°	C]	Toler	rance [ppm/°C]	
			C□ :	0	CG,CH, CJ, (∩K		G:±30	
		Standard	00.	0	00,011, 00, 0	UK .		H:±60	
	Temperature	Stanuaru	U🗆 :	- 750	UJ, UK			J:±120	
	Compensating(Class1)							K:±250	
			SL :	+350 to -100	0				
		High Frequency Type	Tem	perature Charac	teristic [ppm/°	C]	Toler	rance [ppm/°C]	
		Figh Frequency Type	C□ :	0	СН			H:±60	
Specified					Capacitance	Ret	ference		
/alue				Specification	change	tem	perature	Temperature Range	
				В	±10%	:	20°C	−25 to +85°C	
			BJ	X5R	±15%	:	25°C	−55 to +85°C	
	High Permittivity (Class2	\ \	B7	X7R	±15%		25°C	−55 to +125°C	
	High Permittivity (Glassz)	C6	X6S	±22%	:	25°C	−55 to +105°C	
			C7	X7S	±22%	:	25°C	−55 to +125°C	
			D7	X7S	+22/-33%		25°C	−55 to +125°C	
			LD())	X5R	±15%	:	25°C	−55 to +85°C	
			Note : 🗦	KLD Low disto	rtion high value i	multila	yer cerami	ic capacitor	
	Class 1 Capacitance at 20°C and following equation. $\frac{(C_{85}-C_{20})}{C_{20}\times\Delta T} \times T$	10^{6} (ppm/°C)	d in thern T=65	nal equilibrium, a	and the tempera	ture c	haracteris	tic shall be calculated	l from t
est lethods and Remarks	Class 2 Capacitance at each step equation.	shall be measured in the	ermal equ	librium, and the	temperature cha	aracter	istic shall	be calculated from th	e followi
	Step	В		X5R、X7R、X6S、	X7S、X7T				
	1	Minimum ope	erating te						
	2	20°C		25°C					
	3	Maximum ope	erating te	mperature					



 $\frac{(C-C_2)}{C_2} \times 100(\%)$

C : Capacitance in Step 1 or Step 3 C2 : Capacitance in Step 2

9. Deflection Appearance : No abnormality Standard Capacitance change : Within $\pm 5\%$ or ± 0.5 pF, whichever is larger. Temperature Compensating(Class1) Appearance : No abnormality Specified High Frequency Type Cpaitance change : Within $\pm 0.5 \text{ pF}$ Value Appearance : No abnormality High Permittivity (Class2) Capacitance change : Within ±12.5% (BJ, B7, C6, C7, D7, LD(🔆)) Note: XLD Low distortion high value multilayer ceramic capacitor Multilayer Ceramic Capacitors ^{**1}105 Type 042, 063, The other types Board Glass epoxy-resin substrate Warr Test Thickness 0.8mm 1.6mm Methods and Warp 1mm (Soft Termination type:3mm) Remarks Duration 10 sec. ^{*1:}105 Type thickness, C: 0.2mm ,P: 0.3mm. (Unit: mm) Capacitance measurement shall be conducted with the board bent

10. Body Stren	gth		
0.15.1	Temperature	Standard	1
Specified Value	Compensating(Class1)	High Frequency Type	No mechanical damage.
	High Permittivity (Class2))	1
Test Methods and Remarks	High Frequency Type Applied force : 5N Duration : 10 sec.	← A → X	R0.5 Pressing jig Chip Chip

11. Adhesive S	trength of Terminal Elec	trodes		
	Temperature	Standard		
Specified Value	Compensating(Class1)) High Frequency Ty	be No terminal separati	on or its indication.
Value	High Permittivity (Cla	ss2)		
		Multilayer Cera	mic Capacitors	Hooked jig
Test		042, 063 Type	105 Type or more	
Methods and	Applied force	2N	5N	R=05 Deard
Remarks	Duration	30±5	5 sec.	

12. Solderability	ļ			
0 15 1	Temperature	Standard		
Specified Value	Compensating(Class1)	High Frequency Type	At least 95	% of terminal electrode is covered
Value	High Permittivity (Class2))		
Test		Eutectic so	older	Lead-free solder
Test Methods and	Solder type	H60A or H	63A	Sn-3.0Ag-0.5Cu
Remarks	Solder temperature	230±5°	С	245±3°C
Remarks	Duration		4 ±1	1 sec.



13. Resistance	to Soldering					
Specified Value	Temperature	Standard	Appearance: No abnormalityCapacitance change: Within ±2.5% or ±0.25pF, whichever is larger.Q: Initial valueInsulation resistance: Initial valueWithstanding voltage(between terminals) : No abnormality			
	Compensating(Class1) High Frequency Type	Appearance : No abnormality Capacitancecange : Within ±2.5% Q : Initial value Insulation resistance : Initial value Withstanding voltage (between terminals) : No abnormality			
	High Permittivity(Cla	ss2) Note 1	Appearance: No abormalityCapactace change: Within ±7.5% (BJ, B7, C6, C7, D7, LD(X))Dissipation factor: Initial valueInsulation resistance: Initial valueWithstanding voltage(between terminals): No abnormalityNote: XLD Low distortion high value multilayer ceramic capacitor			
			lss 1			
	Preconditioning	042, 063 Type	105 Type None			
			$80 \text{ to } 100^{\circ}\text{C} 2 \text{ to } 5 \text{ min}$			
	Preheating	150°C, 1 to 2 min.	n. 150 to 200°C, 2 to 5 min.			
	Solder temp.		270±5°C			
	Duration		3±0.5 sec.			
Test Methods and	Recovery	6 to 24 hrs (Standard condition) Noe 5				
Remarks			Class 2			
		042、063 Type	105, 107, 212 Туре 316, 325 Туре			
	Preconditioning		Thermal treatment (at 150°C for 1 hr) Note 2			
	Preheating	150°C, 1 to 2 min.	80 to 100°C, 2 to 5 min. 80 to 100°C, 5 to 10 min.			
	Saldau to ma		150 to 200°C, 2 to 5 min. 150 to 200°C, 5 to 10 min.			
	Solder temp. Duration		270±5°C 3±0.5 sec.			
	Recovery		24±2 hrs(Standard condition)Note 5			
	Recovery					
		、				
14. Temperatu	re Cycle (Thermal Shock	.)				
	Temperature	Standard	Appearance : No abnormality Capacitance change : Within ±2.5% or ±0.25pF, whichever is larger. Q : Initial value Insulation resistance : Initial value Withstanding voltage (between terminals) : No abnormality			
Specified Value	Compensating(Class1) High Frequency Type	Appearance : No abnormality Capacitance change : Within ±0.25pF Q : Initial value Insulation resistance : Initial value			

Specified		High Frequency Type	Q	: Init	tial value		
Value			Insulation resistance	: Init	tial value		
			Withstanding voltage	(bet	tween terminals):N	lo abnormality	
					abnormality		
			Capacitance change	: Wit	hin \pm 7.5% (BJ, B7,	C6, C7, D7, LD(※)))
			Dissipation factor	: Init	ial value		
	High Permittivity (Class2) Note I	Insulation resistance	: Init	ial value		
			Withstanding voltage	(bet	ween terminals): N	lo abnormality	
			Note: XLD Low distort	Note: XLD Low distortion high value multilayer ceramic capacitor			
			Class 1 Class 2				
	Due en ditiening		None		Thermal treatment (at 150°C for 1 hr)		
	Preconditioning		Norie		Note 2		
Test		Step	Tempera	ature	(°C)	Time(min.)	
		1	Minimum opera	iting t	emperature	30±3	
Methods and	1 cycle	2	Normal te	emper	rature	2 to 3	
Remarks		3	Maximum opera	ting 1	temperature	30±3	
		4	Normal te	emper	rature	2 to 3	
	Number of cycles	5 times					
	Recovery	6 to 24 hrs(Sta	andard condition)Note 5		24±2 hrs(Standard condition)	Note 5



15. Humidity (Steady State)					
Specified Value	Temperature Compensating(Class))	Appearance Capacitance change Q Insulation resistance	: C<10pF : Q≧200+10C 10≦C<30pF : Q≧275+2.5C C≧30pF:Q≧350(C:Nominal capacitance)		
		High Frequency Type	Appearance Capacitance change Insulation resistance	: No abnormality : Within ±0.5pF, : 1000 MΩmin.		
	High Permittivity(Cl	Appearance Capacitance change Dissipation factor Insulation resistance Note: ※LD Low distor	: Wit : 5.0 : 50	abnormality thin \pm 12.5% (BJ, B7, C6, C7, D7, LD(\otimes)) % max.(BJ, B7, C6, C7, D7, LD(\otimes)) M $\Omega\mu$ F or 1000 M Ω whichever is smaller. gh value multilayer ceramic capacitor		
	C		ass 1		Class 2	
		Standard	High Frequency Typ	be	All items	
Test	Preconditioning	Ν	one		Thermal treatment (at 150°C for 1 hr) Note 2	
Methods and	Temperature	40±2°C	60±2°C		40±2°C	
Remarks	Humidity	90 to	o 95%RH		90 to 95%RH	
	Duration	500+2	4/−0 hrs		500+24/-0 hrs	
	Recovery	6 to 24 hrs(Standa	ard condition)Note 5		24 \pm 2 hrs(Standard condition)Note 5	

16. Humidity Lo	pading			
Specified Value	Temperature	Standard	Appearance Capacitance change Q Insulation resistance	: No abnormality : Within $\pm 7.5\%$ or $\pm 0.75pF$, whichever is larger. : C $< 30pF$: Q $\ge 100 + 10C/3$ C $\ge 30pF$: Q ≥ 200 (C:Nominal capacitance) : 500 M Ω min.
	Compensating(Class1)	High Frequency Type	Appearance Capacitance change Insulation resistance	: No abnormality : C≦2pF:Within ±0.4 pF C>2pF:Within ±0.75 pF (C:Nominal capacitance) : 500 MΩmin.
	High Permittivity(Class2) Note 1	Appearance Capacitance change Dissipation factor Insulation resistance Note: XLD Low distort	: No abnormality : Within $\pm 12.5\%$ (BJ, B7, C6, C7, D7, LD($\%$)) : 5.0% max. (BJ, B7, C6, C7, D7, LD($\%$)) : 25 M $\Omega\mu$ F or 500 M Ω whichever is smaller. ion high value multilayer ceramic capacitor
		C	Class 1	Class 2
		Standard	High Frequency Typ	e All items
	Preconditioning	None		Voltage treatment (Rated voltage are applied for 1 hour at 40°C) Note 3
Test	Temperature	40±2°C	60±2°C	40±2°C
Methods and	Humidity	90 t	o 95%RH	90 to 95%RH
Remarks	Duration	500+	24/—0 hrs	500+24/-0 hrs
	Applied voltage	Rate	ed voltage	Rated voltage
	Charge/discharge current	50r	mA max.	50mA max.
	Recovery	6 to 24 hrs(Stan	dard condition)Note 5	24 ± 2 hrs(Standard condition) Note 5



17. High Temp	erature Loading					
Specified Value	Temperature Compensating(Class1)	Standard	Appearance Capacitance change Q Insulation resistance	:C<10pF:Q≧ 10≦C<30pF: C≧30pF:Q≧	±0.3pF, whichever is 200+10C	
		High Frequency Type	Appearance: No abnormalityency TypeCapacitance change: Within $\pm 3\%$ or ± 0.3 pF, whichever is larger.Insulation resistance: 1000 MΩmin.			s larger.
	High Permittivity(Class2) Note 1	Appearance Capacitance change Dissipation factor Insulation resistance Note: ※LD Low dist	: 5.0% max.(BJ, : 50 M <i>Ωμ</i> F or 10	(BJ, B7, C6, C7, D7 B7, C6, C7, D7, LD(※ 000 M Ω whichever is	()) smaller.
		Clas	s 1	Class 2		
		Standard H	ligh Frequency Type	BJ, LD(🔆)	C6	B7, C7, D7
	Preconditioning	None		Voltage treatment (Twice the rated voltage shall be applied for 1 hour at 85°C, 105°C or 125°C) Note 3, 4		
Test	Temperature	Maximum operating temperature		Maximum operating temperature		
Methods and	Duration	1000+48/-0 hrs		1000+48/-0 hrs		
Remarks	Applied voltage	Rated vol	tage × 2	Rated voltage × 2 Note 4		
nomuno	Charge/discharge current	50mA max.		50mA max.		
	Recovery	6 to 24hr(Standard condition)Note 5		24 \pm 2 hrs(Standard condition)Note 5		

Note 1 The figures indicate typical specifications. Please refer to individual specifications in detail.

Note 2 Thermal treatment : Initial value shall be measured after test sample is heat-treated at $150+0/-10^{\circ}$ C for an hour and kept at room temperature for 24 ± 2 hours.

Note 3 Voltage treatment : Initial value shall be measured after test sample is voltage-treated for an hour at both the temperature and voltage specified in the test conditions, and kept at room temperature for 24±2hours.

Note 4 150% of rated voltage is applicable to some items. Please refer to their specifications for further information.

Note 5 Standard condition: Temperature: 5 to 35°C, Relative humidity: 45 to 85 % RH, Air pressure: 86 to 106kPa When there are questions concerning measurement results, in order to provide correlation data, the test shall be conducted under the following condition.

Temperature: 20±2°C, Relative humidity: 60 to 70 % RH, Air pressure: 86 to 106kPa Unless otherwise specified, all the tests are conducted under the "standard condition".

RELIABILITY DATA

1. Operating Temp	1. Operating Temperature Range				
	Temperature Compensating(High Frequency type) CG(C0G) : -55 to +125°C				
Specified Value	High permittivity X7R, X7S : -55 to $+125^{\circ}$ C X5 : -55 to $+85^{\circ}$ C B : -25 to $+85^{\circ}$ C				

2. Storage Temper	. Storage Temperature Range				
	Temperature Compensating(High Frequency type) CG(C0G) : -55 to $+125^{\circ}$ C				
Specified Value	High permittivity X7R, X7S : -55 to $+125^{\circ}$ C X5R : -55 to $+85^{\circ}$ C B : -25 to $+85^{\circ}$ C				

3. Rated Voltage	
Specified Value	100VDC(HMK,HMJ), 250VDC(QMK,QMJ,QVS), 630VDC(SMK,SMJ)

4. Withstanding Volt	age(Between terminals)	
Specified Value	No breakdown or damage	
Test Methods and Remarks	Applied voltage Duration Carge/discharge current	: Rated voltage × 2.5(HMK,HMJ), Rated voltage × 2(QMK,QMJ,QVS), Rated voltage × 1.2(SMK,SMJ) : 1 to 5sec. : 50mA max.

5. Insulation Resist	ance	
Specified Value	Temperature Compensating 10000M Ω min High permittivity 100M $\Omega\mu$ or 10G Ω whichev	
Test Methods and Remarks	Applied voltage Duration Charge/discharge current	: Rated voltage(HMK,HMJ, QMK,QMJ,QVS), 500V(SMK,SMJ) : 60±5sec. : 50mA max.

6. Capacitance (To	6. Capacitance (Tolerance)				
Specified Value	Temperature Compensating(High Frequency type) $\pm 0.1 pF (C < 5 pF) \pm 0.25 pF (C < 10 pF) \pm 0.5 pF (5 pF \le C < 10 pF) \pm 2\%(C=10 pF) \pm 5\%(C \ge 10 pF)$ High permittivity $\pm 10\%, \pm 20\%$				
Test Methods and Remarks	Temperature Compensatir Measuring frequency Measuring voltage Bias application High permittivity Measuring frequency Measuring voltage Bias application	ng(High Frequency type) : 1MHz±10% : 0.5 to 5Vrms : None : 1kHz±10% : 1±0.2Vrms : None			

7. Q or Dissipation	Factor			
	Temperature Compensa	ating(High Frequency type)		
	C < 30pF : Q≧800+20C			
	C≧30pF:Q≧1400	C:Normal Capacitance(/pF)		
Specified Value				
	High permittivity			
	3.5%max(HMK,HMJ)			
	2.5%max(QMK,QMJ, SM	IK,SMJ)		
	Temperature Compensa	ating(High Frequency type)		
	Measuring frequency	: 1MHz±10%		
	Measuring voltage	: 0.5 to 5Vrms		
Test Methods and	Bas application	: None		
Remarks				
Kondiks	High permittivity			
	Measuring frequency	: 1kHz±10%		
	Measuring voltage	: 1±0.2Vrms		
	Bas application	: None		

8. Temperature Cha	aracteristic of Capacitance					
	Temperature Compensating(High Frequency type)COG:±30ppm(25 to +125°C)					
Specified Value	High permittivity B : $\pm 10\%(-25 \text{ to } +85^{\circ}\text{C})$ X5R : $\pm 15\%(-55 \text{ to } +85^{\circ}\text{C})$ X7R : $\pm 15\%(-55 \text{ to } +125^{\circ}\text{C})$ X7S : $\pm 22\%(-55 \text{ to } +125^{\circ}\text{C})$					
Test Methods and Remarks	Temperature Compensating(High Frequency type) Capacitance at 25°C and 85°C shall be measured in thermal equilibrium, and the temperature characteristic shall be calculated from the following equation. $\frac{(C_{85}-C_{25})}{C_{25} \times \Delta T}$ $\times 10^6 \times [ppm/^{\circ}C]$ High permittivity Capacitance value at each step shall be measured in thermal equilibrium, and the temperature characteristic shall be calculated from the following equation. Step B X5R, X7R, X7S					
Remarks	1 Minimum operating tempeature 2 20°C 25°C					
	3 Maximum operating temperature					
	$\frac{(C-C_2)}{C_2} \times 100(\%)$ C : Capacitance value in Step 1 or Step 3 C2 : Capacitance value in Step 2					

9. Deflection Yemperature Compensating(High Frequency type) Appearance : No abnormality Capacitance change :±5% or ±0.5pF, whichever is larger. High permittivity Appearance : No abnormality Capacitance change : No abnormality Capacitance change : Within±10%

	Capacitance of	change : Within±10%	
Test Methods and Remarks	Warp Duration Test board Thicknss	: 1mm (Soft Termination type:3mm) : 10sec. : Glass epoxy-resin substrate : 1.6mm	Board $\overrightarrow{B_{r-230}}$ Warp 45 ± 2 45 ± 2 (Unit: mm)
	Capacitance r	neasurement shall be conducted with the b	oard bent.



10. Adhesive Stren	th of Terminal Electrodes
Specified Value	No terminal separation or its indication.
Test Methods and Remarks	Temperature Compensating(High Frequency type)Applied force: 2NDuration: $10\pm 5 \text{ sec.}$ High permittivityApplied force: 5NDuration: $30\pm 5 \text{ sec.}$

11. Solderability						
Specified Value	At least 95% of terminal elect	At least 95% of terminal electrode is covered by new solder				
		Eutectic solder	Lead-free solder			
Test Methods and	Solder type	H60A or H63A	Sn-3.0Ag-0.5Cu			
Remarks	Solder temperature	230±5°C	245±3°C			
	Duration	4±1	sec.			

12. Resistance to S	Soldering					
	Temperature Compensating(High Frequency type)					
	Appearance	: No abnormality				
	Capacitance change	: C \approx 10pF :±0.25pF C \approx 10pF :±2.5% \approx Normal capacitance				
	Insulation resistance	: Initial value				
	Withstanding voltage	(between terminals) : No abnormality				
Specified Value	Specified Value High permittivity					
	Appearance	: No abnormality				
	Capacitance change	: Within±15%(HMK,HMJ), ±10%(QMK,QMJ, SMK,SMJ)				
	Dissipation factor	: Inital value				
	Insulation resistance	: Initial value				
	Withstanding voltage	(between terminals) : No abnormality				
	Preconditioning	: Thermal treatment(at 150°C for 1hr) Note1 (Only High permittivity)				
Test Methods and	Solder temperature	: 270±5°C				
Remarks	Duration	: 3±0.5sec.				
Remarks	Preheating conditions	: 80 to 100°C, 2 to 5 min. 150 to 200°C, 2 to 5min.				
	Recovery	: 24 \pm 2hrs under the stadard condition Note3				

13. Temperature C	ture Cycle(Thermal Shock)						
	Temperature C	Temperature Compensating(High Frequency type)					
	Appearance	: No abnormality	: No abnormality				
	Capacitance ch	nange : C‰≦10pF:±0.25% C‰>10pF	: C※≦10pF :±0.25% C※>10pF :±2.5%				
	Insulation resis	tance : Initial value	: Initial value				
	Withstanding vo	oltage (between terminals):No abnormali	ty				
Specified Value	High permittivit	У					
	Appearance	: No abnormality					
	Capacitance ch	hange : Within $\pm 15\%$ (HMK,HMJ), $\pm 7.5\%$ (G	: Within \pm 15%(HMK,HMJ), \pm 7.5%(QMK,QMJ, SMK,SMJ)				
	Dissipation fact	tor : Initial value	: Initial value				
	Insulation resis	tance : Initial value	: Initial value				
	Withstanding vo	oltage (between terminals) : No abnormali	(between terminals) : No abnormality				
	Preconditioning	: Thermal treatment (at 150°C for 1hr) Note	31				
	Conditions for	1 cycle					
	Step	temperature (°C)	Time(min.)				
Test Methods and	1	Minimum operating temperature	30 ± 3 min.				
Remarks	2	Normal temperature	2 to 3min.				
Remarks	3	Maximum operating temperature	30 ± 3 min.				
	4	Normal temperature	2 to 3min.				
	Number of cycl	es : 5 times					
	Recovery : 24±2hrs under the standard condition Note3						



14. Humidity(Stea	dy state)	
	Temperature Compensati	ng(High Frequency type)
	Appearance	: No abnormality
	Capacitance change	: C※≦10pF :±0.5pF C※>10pF :±5% ※Normal capacitance
	Insulation resistance	: 1000M Ωmin
Specified Value	High permittivity	
	Appearance	: No abnormality
	Capacitance change	: Within $\pm 15\%$
	Dissipation factor	: 7%max(HMK,HMJ), 5%max(QMK,QMJ, SMK,SMJ).
	Insulation resistance	: 25M $\Omega\mu$ or 1000M Ω , whichever is smaller.
	Preconditioning	: Thermal treatment(at 150°C for 1hr) Note1 (Only High permittivity)
Test Methods and	Temperature	: 40±2°C
Remarks	Humidity	: 90 to 95%RH
Remarks	Duration	: 500 +24/-0 hrs
	Recovery	: 24 \pm 2hrs under the standard condition Note3

15. Humidity Loadir	ng					
	Temperature Compensating(High Frequency type)					
	Appearance	: No abnormality				
	Capacitance change	:C‰≦2.0pF:±0.4pF 2.0pF <c≦10pf: c‰="" ±0.75pf="">10pF:±7.5%</c≦10pf:>				
		: XNormal capacitance				
	Insulation resistance	: 500M Ωmin				
Specified Value						
	High permittivity					
	Appearance	: No abnormality				
	Capacitance change	: Within±15%				
	Dissipation factor	:7%max(HMK,HMJ), 5%max(QMK,QMJ, SMK,SMJ).				
	Insulation resistance	: 10M $\Omega\mu$ F or 500M Ω whichever is smaller.				
	According to JIS 5102 claus	se 9.9.				
	Preconditioning	: Voltage treatment Note2 (Only High permittivity)				
	Temperature	:40±2°C				
Test Methods and	Humidity	: 90 to 95%RH				
Remarks	Applied voltage	: Rated voltage				
	Charge/discharge current	: 50mA max.				
	Duration	: 500 +24/-0 hrs				
	Recovery	: 24 \pm 2hrs under the standard condition Note3				

16. High Temperatu	ire Loading					
	Temperature Compensating(High Frequency type)					
	Appearance : No abnormality					
	Capacitance change	: C‰≦10pF :±0.3pF C‰>10pF :±3%				
	Insulation resistance	:1000M Ωmin				
Specified Value	High permittivity					
	Appearance	: No abnormality				
	Capacitance change	: Within±15%				
	Dissipation factor	: 7%max(HMK,HMJ), 5%max(QMK,QMJ, SMK,SMJ).				
	Insulation resistance	: 50M $\Omega\mu$ F or 1000M Ω whichever is smaller.				
	According to JIS 5102 clause 9.10.					
	Preconditioning	: Voltage treatment Note2 (Only High permittivity)				
Test Methods and	Temperature	: Maximum operating temperature				
Remarks	Applied voltage	: Rated voltage × 2(HMK,HMJ,QVS) Rated voltage × 1.5 (QMK,QMJ) Rated voltage × 1.2 (SMK,SMJ)				
Remarks	Charge/discharge current	: 50mA max.				
	Duration	: 1000 +24/-0 hrs				
	Recovery	: 24 \pm 2hrs under the standard condition Note3				
Note1 Thermal treatme		d after test sample is heat-treated at 150 \pm 0 $/-$ 10 $^\circ$ C for an hour and kept at room temperature				
	for 24 ± 2 hours.					
Note2 Voltage treatme		ed after test sample is voltage-treated for an hour at both the temperature and voltage specified in				
Note3 Standard condit		l kept at room temperature for 24±2hours. elative humidity: 45 to 85 % RH, Air pressure: 86 to 106kPa				
		concerning measurement results, in order to provide correlation data, the test shall be conducted				
	under the following conditio					
	Temperature: $20\pm2^{\circ}$ C, Rela	ative humidity: 60 to 70 % RH, Air pressure: 86 to 106kPa				
	Unless otherwise specified,	all the tests are conducted under the "standard condition".				

This catalog contains the typical specification only due to the limitation of space. When you consider the purchase of our products, please check our specification.

For details of each product (characteristics graph, reliability information, precautions for use, and so on), see our Web site (http://www.ty-top.com/).

PRECAUTIONS

1. Circuit Design	
	♦Verification of operating environment, electrical rating and performance
	1. A malfunction of equipment in fields such as medical, aerospace, nuclear control, etc. may cause serious harm to human life or have severe social ramifications.
	Therefore, any capacitors to be used in such equipment may require higher safety and reliability, and shall be clearly differentiated from them used in general purpose applications.
Precautions	♦ Operating Voltage (Verification of Rated voltage)
	1. The operating voltage for capacitors must always be their rated voltage or less.
	If an AC voltage is loaded on a DC voltage, the sum of the two peak voltages shall be the rated voltage or less.
	For a circuit where an AC or a pulse voltage may be used, the sum of their peak voltages shall also be the rated voltage or less.
	2. Even if an applied voltage is the rated voltage or less reliability of capacitors may be deteriorated in case that either a high frequency AC voltage or a pulse voltage having rapid rise time is used in a circuit.

2. PCB Design									
-	♦Pattern config	urations (Desigr	n of Land-patt	erns)					
	1. When capa	citors are mount	ed on PCBs,	the amount of	f solder used (size of fillet) of	an directly aff	ect the capacit	or performance.
	Therefore, the following items must be carefully considered in the design of land patterns:								
	(1)Excessive solder applied can cause mechanical stresses which lead to chip breaking or cracking. Therefore, please consider								
	appr	opriate land-patt	erns for prope	er amount of so	lder.				
Precautions	(2)When r	more than one co	omponent are	jointly soldered	l onto the same	e land, each con	nponent's solde	ring point shall	be separated by
	sold	er-resist.							
	Pattern config	urations (Capac	itor layout on	PCBs)					
	After capacito	ors are mounted	on boards, the	ey can be subj	ected to mecha	anical stresses	in subsequent r	manufacturing p	orocesses (PCB
	cutting, board	inspection, moun	iting of additio	nal parts, asser	mbly into the ch	iassis, wave solo	dering of the bo	ards, etc.). For	this reason, land
	pattern config	urations and posi	itions of capac	citors shall be o	arefully conside	ered to minimize	e stresses.		
	Pattern config	urations (Desigr	n of Land-patt	erns)					
	The following	diagrams and tab	les show some	e examples of r	ecommended la	and patterns to	prevent excess	ive solder amou	ints.
	(1)Recomme	ended land dimen	sions for typic	al chip capacit	ors				
		r Ceramic Capac	itors : Recomr	mended land dir	mensions		Land pat	terns for PCBs	
	(unit: mm)							Land pattern	0.11
	Wave-so	_	010	010	0.05		Chip car	pacitor	Solder-resist
	Туре	107	212	316	325	<u> </u>		─────┴──└─	`
	Size L	1.6	2.0	3.2	3.2	c [/)
	W	0.8	1.25	1.6	2.5	(┥┝╾┺╬	่╂┅╂╾┥ ┝──′	2
	<u>A</u>	0.8 to 1.0	1.0 to 1.4	1.8 to 2.5	1.8 to 2.5			$\rightarrow \longleftarrow$	
	В	0.5 to 0.8	0.8 to 1.5	0.8 to 1.7	0.8 to 1.7		B A	АВ	
	С	0.6 to 0.8	0.9 to 1.2	1.2 to 1.6	1.8 to 2.5				
							Chip ca	pacitor	
								W	
							1	<u></u>	
							Ĺ		
Technical	Reflow-s	oldering							
considerations	Туре	042	063	105	107	212	316	325	432
	Sizo L	0.4	0.6	1.0	1.6	2.0	3.2	3.2	4.5
	Size W	0.2	0.3	0.5	0.8	1.25	1.6	2.5	3.2
	A	0.15 to 0.25	0.20 to 0.30	0.45 to 0.55	0.8 to 1.0	0.8 to 1.2	1.8 to 2.5	1.8 to 2.5	2.5 to 3.5
	В	0.15 to 0.20	0.20 to 0.30	0.40 to 0.50	0.6 to 0.8	0.8 to 1.2	1.0 to 1.5	1.0 to 1.5	1.5 to 1.8
	С	0.15 to 0.30	0.25 to 0.40	0.45 to 0.55	0.6 to 0.8	0.9 to 1.6	1.2 to 2.0	1.8 to 3.2	2.3 to 3.5
	Note:Reco	ommended land s	ize might be d	lifferent accord	ing to the allow	ance of the size	e of the product	t.	
		5		£	1		LWD	0	
	-	Recommended lar	na aimensions	for reflow-sold	lering				
	(unit: mm)	105	107	212					
	Type	0.52	0.8	1.25					
	Size W	1.0	1.6	2.0				w	
	A .	0.18 to 0.22	0.25 to 0						
	B	0.18 to 0.22	0.23 to 0.4						
	C	0.2 to 0.23	1.5 to 1.				<u>د ،</u>		
		0.0 10 1.1	1.0 to 1.	, 1.3 to	2.1		I L	I	





1–3. When PCB is split, the amount of mechanical stress on the capacitors can vary according to the method used. The following methods are listed in order from least stressful to most stressful: push-back, slit, V-grooving, and perforation. Thus, please consider the PCB, split methods as well as chip location.

3. Mounting	
Precautions	 Adjustment of mounting machine When capacitors are mounted on PCB, excessive impact load shall not be imposed on them. Maintenance and inspection of mounting machines shall be conducted periodically. Selection of Adhesives When chips are attached on PCBs with adhesives prior to soldering, it may cause capacitor characteristics degradation unless the following factors are appropriately checked : size of land patterns, type of adhesive, amount applied, hardening temperature and hardening period. Therefore, please contact us for further information.



	♦ Selection of Flux
	Since flux may have a significant effect on the performance of capacitors, it is necessary to verify the following conditions prior to use;
	(1) Flux used shall be less than or equal to 0.1 wt%(in Cl equivalent) of halogenated content. Flux having a strong acidity content shall not be applied.
	(2) When shall capacitors are soldered on boards, the amount of flux applied shall be controlled at the optimum level.
Precautions	(3)When water-soluble flux is used, special care shall be taken to properly clean the boards.
	◆ Soldering
	Temperature, time, amount of solder, etc. shall be set in accordance with their recommended conditions.
	Sn-Zn solder paste can adversely affect MLCC reliability.
	Please contact us prior to usage of Sn-Zn solder.
	♦ Selection of Flux
	1-1. When too much halogenated substance (Chlorine, etc.) content is used to activate flux, or highly acidic flux is used, it may lead to corrosion of terminal electrodes or degradation of insulation resistance on the surfaces of the capacitors.
Technical considerations	1-2. Flux is used to increase solderability in wave soldering. However if too much flux is applied, a large amount of flux gas may be emitted and may adversely affect the solderability. To minimize the amount of flux applied, it is recommended to use a flux-bubbling system.
	1-3. Since the residue of water-soluble flux is easily dissolved in moisture in the air, the residues on the surfaces of capacitors in high
	humidity conditions may cause a degradation of insulation resistance and reliability of the capacitors. Therefore, the cleaning
	methods and the capability of the machines used shall also be considered carefully when water-soluble flux is used.



◆ Soldering

- · Ceramic chip capacitors are susceptible to thermal shock when exposed to rapid or concentrated heating or rapid cooling.
- Therefore, the soldering must be conducted with great care so as to prevent malfunction of the components due to excessive thermal shock.
- Preheating : Capacitors shall be preheated sufficiently, and the temperature difference between the capacitors and solder shall be within 100 to 130°C.
- · Cooling : The temperature difference between the capacitors and cleaning process shall not be greater than 100°C.



Caution

The ideal condition is to have solder mass(fillet)controlled to 1/2 to 1/3 of the thickness of a capacitor.



②Because excessive dwell times can adversely affect solderability, soldering duration shall be kept as close to recommended times as possible.

③Allowable number of reflow soldering : 2 times max.



[Recommended conditions for eutectic soldering]





Caution

OWave soldering must not be applied to capacitors designated as for reflow soldering only. OAllowable number of wave soldering : 1 times max.



[Recommended conditions for eutectic soldering] [Recommended condition for Pb-free soldering]







Caution

①Use a 50W soldering iron with a maximum tip diameter of 1.0 mm.
②The soldering iron shall not directly touch capacitors.
③Allowable number of hand soldering : 1 times max.

5. Cleaning	
Precautions	 Cleaning conditions 1. When PCBs are cleaned after capacitors mounting, please select the appropriate cleaning solution in accordance with the intended use of the cleaning. (e.g. to remove soldering flux or other materials from the production process.) 2. Cleaning condition shall be determined after it is verified by using actual cleaning machine that the cleaning process does not affect capacitor's characteristics.
Technical considerations	 The use of inappropriate cleaning solutions can cause foreign substances such as flux residue to adhere to capacitors or deteriorate their outer coating, resulting in a degradation of the capacitor's electrical properties (especially insulation resistance). Inappropriate cleaning conditions (insufficient or excessive cleaning) may adversely affect the performance of the capacitors. In the case of ultrasonic cleaning, too much power output can cause excessive vibration of PCBs which may lead to the cracking of capacitors or the soldered portion, or decrease the terminal electrodes' strength. Therefore, the following conditions shall be carefully checked; Ultrasonic output : 20 W/2 or less Ultrasonic frequency : 40 kHz or less Ultrasonic washing period : 5 min. or less

6. Resin coating a	and mold
	1. With some type of resins, decomposition gas or chemical reaction vapor may remain inside the resin during the hardening period or while left under normal storage conditions resulting in the deterioration of the capacitor's performance.
Precautions	2. When a resin's hardening temperature is higher than capacitor's operating temperature, the stresses generated by the excessive heat may lead to damage or destruction of capacitors. The use of such resins, molding materials etc. is not recommended.

7. Handling	
	 Splitting of PCB 1. When PCBs are split after components mounting, care shall be taken so as not to give any stresses of deflection or twisting to the board. 2. Board separation shall not be done manually, but by using the appropriate devices.
Precautions	 Mechanical considerations Be careful not to subject capacitors to excessive mechanical shocks. (1) If ceramic capacitors are dropped onto a floor or a hard surface, they shall not be used. (2) Please be careful that the mounted components do not come in contact with or bump against other boards or components.

Precautions	♦Storage
	 To maintain the solderability of terminal electrodes and to keep packaging materials in good condition, care must be taken to contro temperature and humidity in the storage area. Humidity should especially be kept as low as possible. Recommended conditions
	Ambient temperature : Below 30°C
	Humidity : Below 70% RH
	 The ambient temperature must be kept below 40°C. Even under ideal storage conditions, solderability of capacitor is deteriorated as time passes, so capacitors shall be used within 6 months from the time of delivery. Ceramic chip capacitors shall be kept where no chlorine or sulfur exists in the air. The capacitance values of high dielectric constant capacitors will gradually decrease with the passage of time, so care shall be taken to design circuits. Even if capacitance value decreases as time passes, it will get back to the initial value by a heat treatment at 150°C for 1hour.
Technical considerations	If capacitors are stored in a high temperature and humidity environment, it might rapidly cause poor solderability due to terminal oxidation and quality loss of taping/packaging materials. For this reason, capacitors shall be used within 6 months from the time of delivery. If exceeding the above period, please check solderability before using the capacitors.

